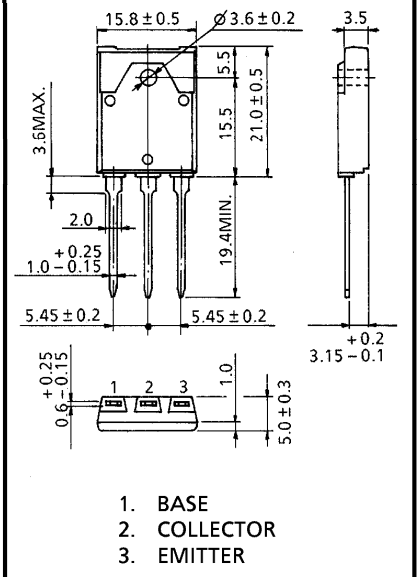
TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE

2SA1804

POWER AMPLIFIER APPLICATIONS

Unit in mm

- Complementary to 2SC4689
- Recommend for 55W High Fidelity Audio Frequency Amplifier output Stage.



JEDEC	—
JEITA	—
TOSHIBA	2-16F1A

Weight : 5.8g (Typ.)

MAXIMUM RATINGS (Tc = 25°C)

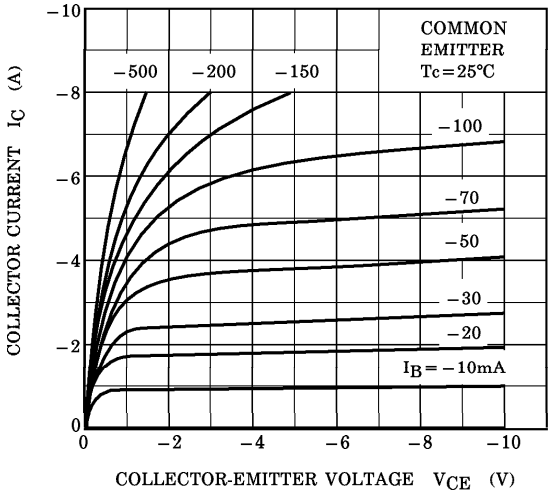
CHARACTERISTIC		SYMBOL	RATING	UNIT
Collector-Base Voltage		V_{CBO}	−120	V
Collector-Emitter Voltage		V_{CEO}	−120	V
Emitter-Base Voltage		V_{EBO}	−5	V
Collector Current	DC	I_C	−8	A
	Pulse	I_{CP}	−16	
Base Current		I_B	−0.8	A
Collector Power Dissipation (Tc = 25°C)		P_C	70	W
Junction Temperature		T_j	150	°C
Storage Temperature Range		T_{stg}	−55~150	°C

ELECTRICAL CHARACTERISTICS (Tc = 25°C)

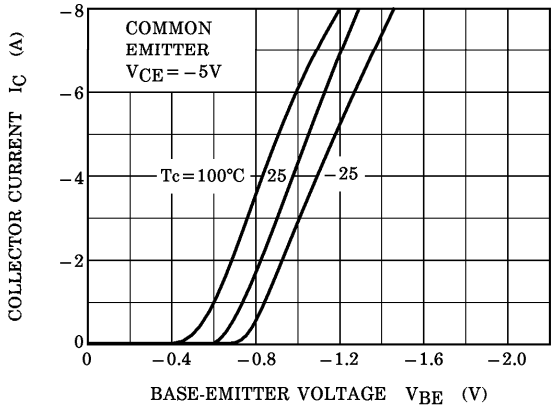
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	V_{CB} = −120V, I_E = 0	—	—	−5.0	μA
Emitter Cut-off Current	I_{EBO}	V_{EB} = −5V, I_C = 0	—	—	−5.0	μA
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	I_C = −50mA, I_B = 0	−120	—	—	V
DC Current Gain	$h_{FE(1)}$ (Note)	V_{CE} = −5V, I_C = −1A	55	—	160	
	$h_{FE(2)}$	V_{CE} = −5V, I_C = −4A	35	75	—	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	I_C = −6A, I_B = −0.6A	—	−0.80	−2.0	V
Base-Emitter Voltage	V_{BE}	V_{CE} = −5V, I_C = −4A	—	−0.97	−1.5	V
Transition Frequency	f_T	V_{CE} = −5V, I_C = −1A	—	30	—	MHz
Collector Output Capacitance	C_{ob}	V_{CB} = −10V, I_E = 0, f = 1MHz	—	420	—	pF

(Note) : $h_{FE\,(1)}$ Classification R : 55~110, O : 80~160

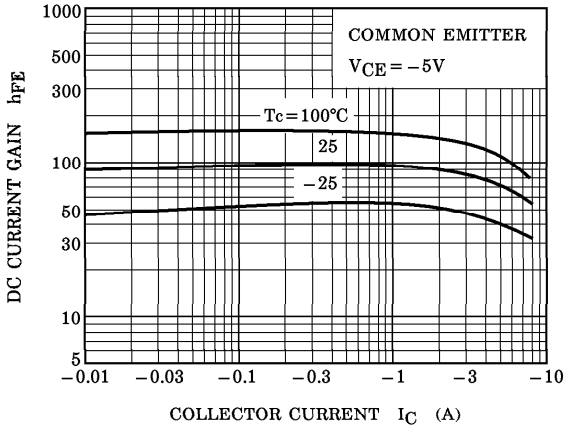
$I_C - V_{CE}$



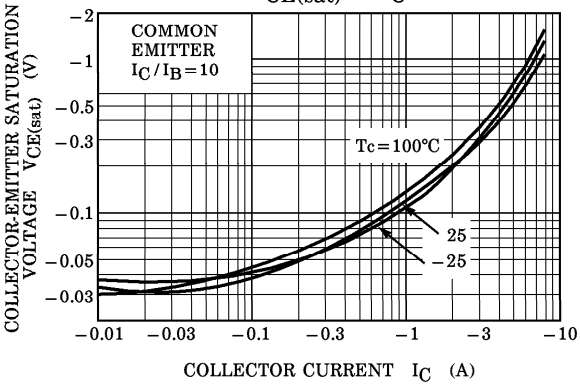
$I_C - V_{BE}$



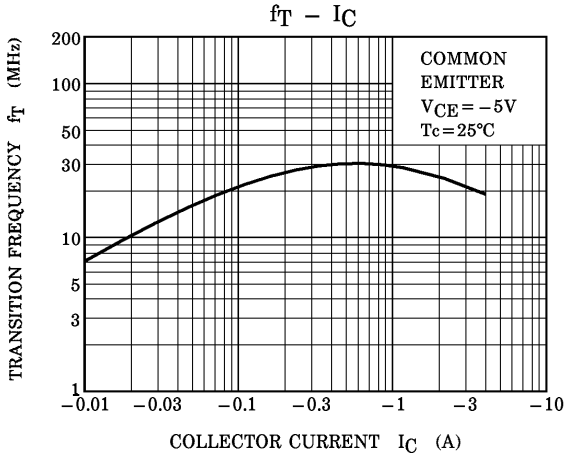
$h_{FE} - I_C$



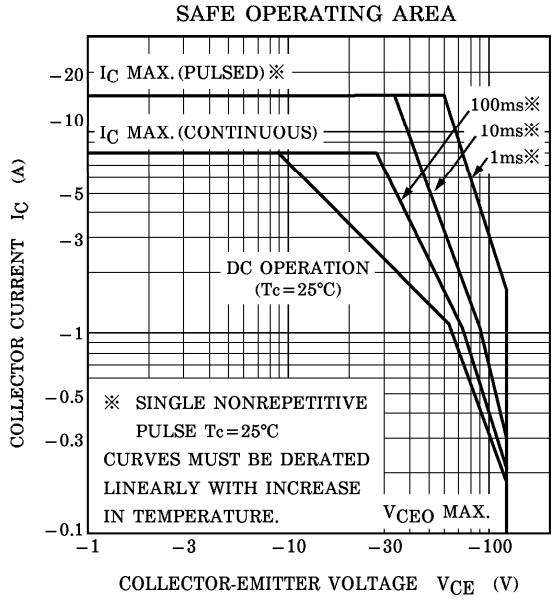
$V_{CE(sat)} - I_C$



$f_T - I_C$



SAFE OPERATING AREA



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